

TISP4P015L1N THRU TISP4P035L1N

LOW CAPACITANCE BIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTOR

TISP4P0xxL1N Overvoltage Protector Series

Designed for ADSL, ADSL2, VDSL, VDSL2 protection

Ion-Implanted Breakdown Region
- Precise and Stable Voltage

Low Voltage Overshoot Under Surge

Low Off-State Capacitance

Device Name	V _{DRM} V	V _(BO) V
TISP4P015L1N	8	15
TISP4P020L1N	12	20
TISP4P025L1N	16	25
TISP4P035L1N	24	35

Rated for International Surge Wave Shapes

Wave Shape	Standard	I _{PPSM} A
8/20	IEC 61000-4-5	30
10/1000	GR-1089-CORE	18

Description

This range of devices is designed to protect xDSL line-driver interfaces from overvoltages up to rated limits. Overvoltages are normally caused by a.c. power-system or lightning-flash disturbances which are induced or conducted onto the telephone line. These symmetrical protectors are two-terminal thyristor-crowbar devices. They can be used to protect between conductors, or a pair of devices can be deployed to protect from line to ground.

When placed between the xDSL line driver IC and the transformer, this protector will clamp and switch into a low-impedance state, safely diverting the energy transferred by the xDSL coupling transformer. The low capacitance design makes this device suitable for designs from ADSL all the way up to 30 MHz VDSL2.

Telecom ports need protection against Common Mode (Longitudinal) and Differential (Metallic) surges, to comply with international standards such as ITU-T K.20, K.21 or K.45, Telcordia GR-1089-CORE and YD/T. Common Mode surges are resisted by the galvanic isolation of the coupling transformer which is commonly rated to 2 kV or greater. Differential surges can be transmitted by the transformer, and can stress the Line Driver Interface IC. As the xDSL interface circuit is designed to operate from 3 kHz to 30 MHz, nearby high frequency events - such as cable flashover or primary protection activation - can generate damaging conditions for the interface requiring this type of protection.

Please contact your Bourns representative if the protection voltage you require is not listed.

How to Order

Device	Package	Carrier	Order As	Marking Code	Reel Quantity
TISP4P0xxL1N	SOT23-5	Embossed Tape Reeled	TISP4P0xxL1NR-S	Pxx	10000

Insert xx corresponding to device name.

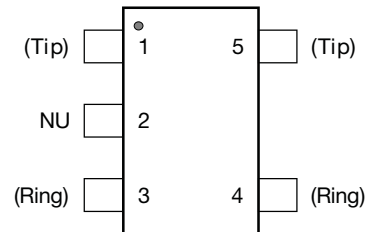
OCTOBER 2009

*RoHS Directive 2002/95/EC Jan 27 2003 including Annex.

Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications.

SOT23-5 Package (Top View)



Terminal typical application names shown in parenthesis.
NU - Non-usable; no external electrical connection should be made to this terminal.

MD-SOT23-5-001-a

Device Symbol



SD-TISP4-002-a

TISP4P0xxL1N Overvoltage Protector Series

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Absolute Maximum Ratings, $T_A = 25\text{ °C}$ (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	'4P015L1N ±8 '4P020L1N ±12 '4P025L1N ±16 '4P035L1N ±24	V
Non-repetitive peak impulse current (see Notes 1, 2 and 3) 8/20 μs (IEC 61000-4-5, 1.2/50 μs voltage, 8/20 current combination wave generator) 10/1000 μs (GR-1089-CORE, 10/1000 μs voltage wave shape)	I_{PPSM}	±30 ±18	A
Junction temperature	T_J	-40 to +150	°C
Storage temperature range	T_{stg}	-65 to +150	°C

- NOTES: 1. Initially the device must be in thermal equilibrium with $T_J = 25\text{ °C}$.
 2. The surge may be repeated after the device returns to its initial conditions.
 3. Rated currents only apply if pins 1 & 5 (Tip) are connected together and pins 3 & 4 (Ring) are connected together.

Electrical Characteristics, $T_A = 25\text{ °C}$ (Unless Otherwise Noted)

Parameter	Test Conditions	Min	Typ	Max	Unit
I_{DRM} Repetitive peak off-state current	$V_D = V_{\text{DRM}}$			±1	μA
$V_{(\text{BO})}$ Breakover voltage	$dv/dt = \pm 250\text{ V/ms}$, $R_{\text{SOURCE}} = 300\ \Omega$			±15 ±20 ±25 ±35	V
I_H Holding current	$I_T = \pm 5\text{ A}$, $di/dt = \pm 30\text{ mA/ms}$		±30 ±10 ±30 ±30		mA
C_O Off-state capacitance	$f = 1\text{ MHz}$, $V_d = 1\text{ V rms}$, $V_D = 2\text{ V}$		6.5 6 5.5 3.5		pF
ΔC Delta-capacitance	$f = 1\text{ MHz}$, $V_d = 1\text{ V rms}$, $V_D = 1\text{ V to } V_{\text{DRM}}$		2 2.5 3 2		pF

Parameter Measurement Information

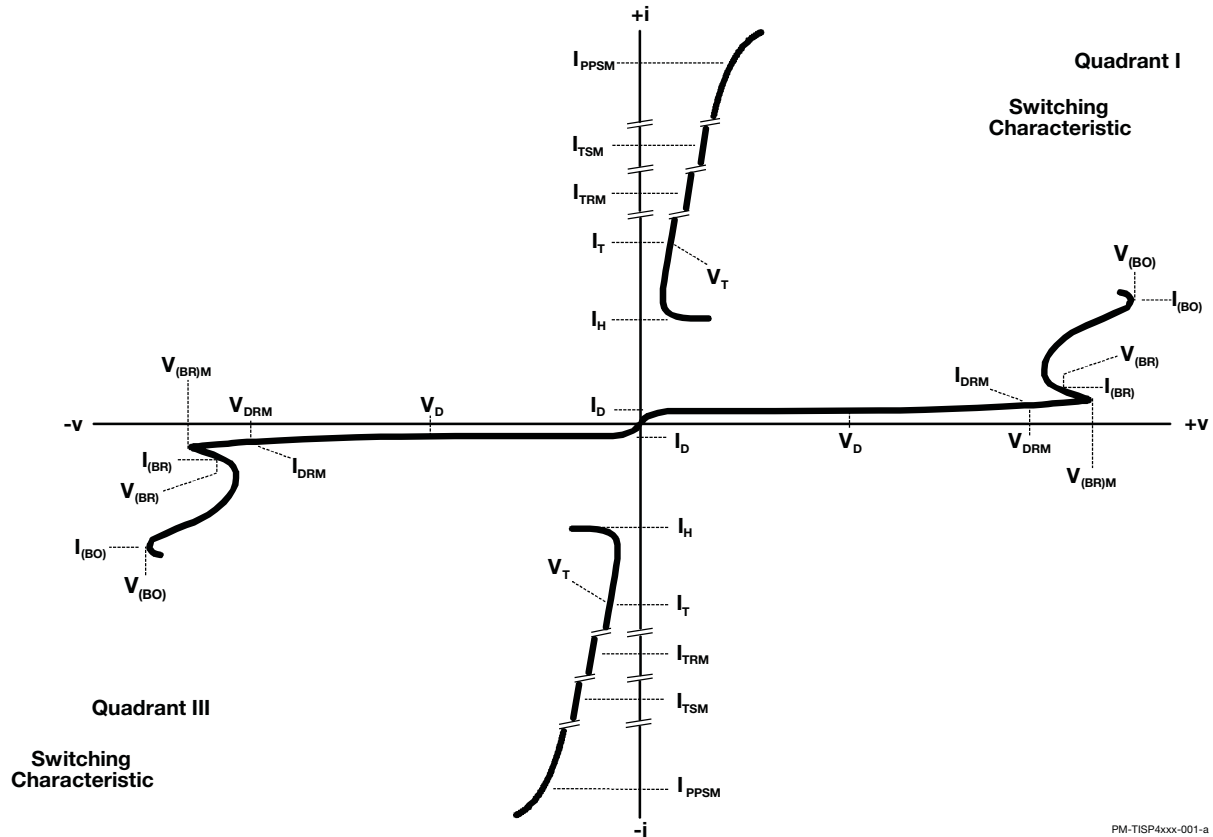
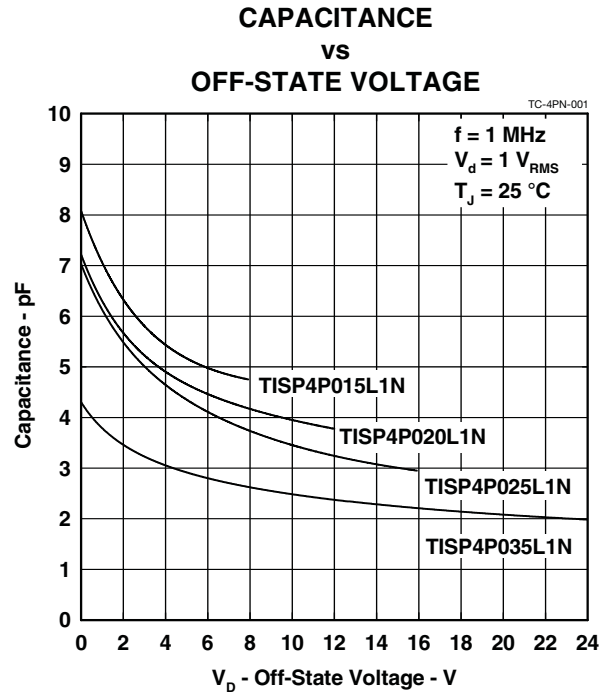


Figure 1. Voltage-Current Characteristic for Tip and Ring Terminals
All Measurements are Referenced to the Ring Terminal

PM-TISP4xxx-001-a

Typical Characteristics



TISP4P0xxL1N Overvoltage Protector Series

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VDSL Application Examples

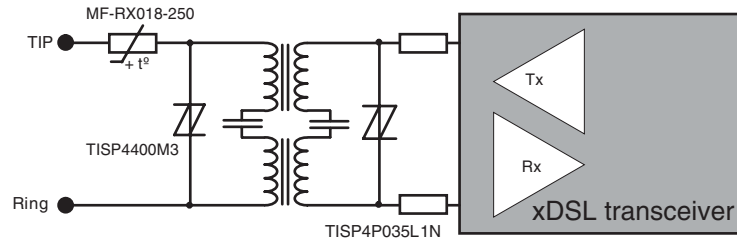


Figure 3.

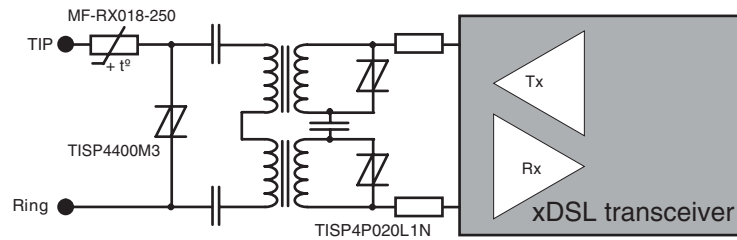


Figure 4.

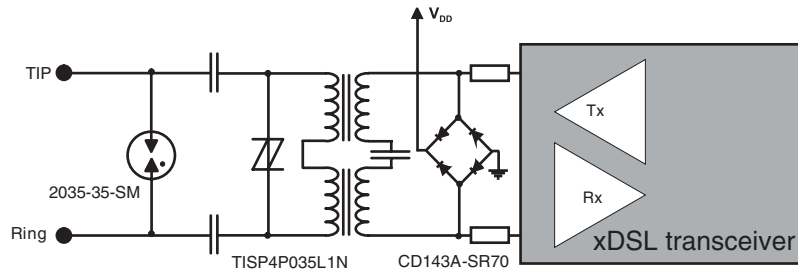
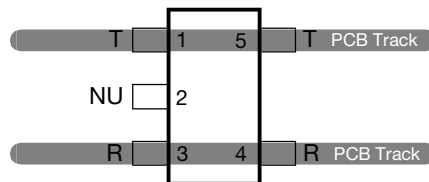


Figure 5.

Recommended PCB Layout



MD-SOT223-5-xxx

Figure 6.

Bourns Sales Offices

Region	Phone	Fax
The Americas:	+1-951-781-5500	+1-951-781-5700
Europe:	+41-41-7685555	+41-41-7685510
Asia-Pacific:	+886-2-25624117	+886-2-25624116

Technical Assistance

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9